

1.2MHz, 0.4V/µs Over-The-Top™ Micropower Rail-to-Rail Input and Output Op Amps

### **FEATURES**

- Operates with Inputs Above V+
- Rail-to-Rail Input and Output
- Low Power: 230µA per Amplifier Max
- Gain Bandwidth Product: 1.2MHz
- Slew Rate: 0.4V/us
- High Output Current: 25mA Min
- Specified on 3V, 5V and ±15V Supplies
- Reverse Battery Protection to 18V
- No Supply Sequencing Problems
- High Voltage Gain: 1500V/mV
- Single Supply Input Range: -0.4V to 44V
- High CMRR: 98dB
- No Phase Reversal

### **APPLICATIONS**

- Battery- or Solar-Powered Systems Portable Instrumentation Sensor Conditioning
- Supply Current Sensing
- Battery Monitoring
- Micropower Active Filters
- 4mA to 20mA Transmitters

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Over-The-Top is a trademark of Linear Technology Corporation.

### DESCRIPTION

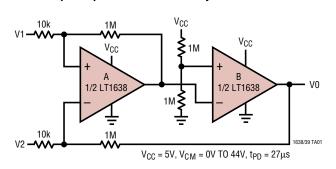
The LT<sup>®</sup>1638 is a low power dual rail-to-rail input and output operational amplifier available in the standard 8-pin PDIP and SO packages as well as the 8-lead MSOP package. The LT1639 is a low power quad rail-to-rail input and output operational amplifier offered on the standard 14-pin PDIP and surface mount packages.

The LT1638/LT1639 op amps operate on all single and split supplies with a total voltage of 2.5V to 44V drawing only 170 $\mu$ A of quiescent current per amplifier. These amplifiers are reverse battery protected and draw no current for reverse supply up to 18V.

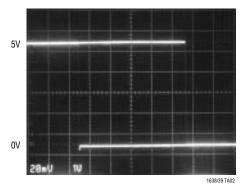
The input range of the LT1638/LT1639 includes both supplies, and a unique feature of this device is its capability to operate over the top with either or both of its inputs above V<sup>+</sup>. The inputs handle 44V, both differential and common mode, independent of supply voltage. The input stage incorporates phase reversal protection to prevent false outputs from occurring even when the inputs are 22V below the negative supply. Protective resistors are included in the input leads so that current does not become excessive when the inputs are forced below the negative supply. The LT1638/LT1639 can drive loads up to 25mA and still maintain rail-to-rail capability. The op amps are unity-gain stable and drive all capacitive loads up to 1000pF when optional output compensation is used.

## TYPICAL APPLICATION

#### Over-The-Top Comparator with 100mV Hysteresis Centered at 0mV



#### **Output Voltage vs Input Voltage**

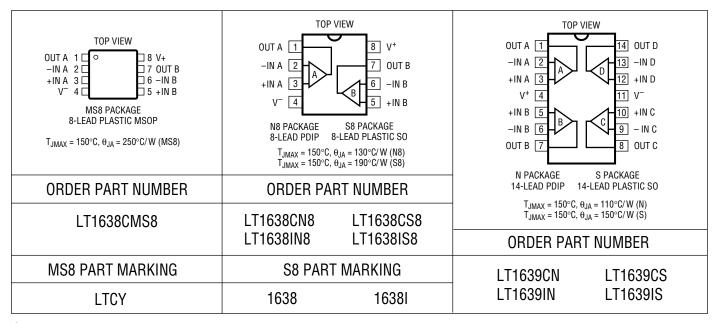




# **ABSOLUTE MAXIMUM RATINGS** (Note 1)

| Total Supply Voltage (V <sup>+</sup> to V <sup>-</sup> ) | 44V           |
|--|---------------|
| Input Differential Voltage                               | 44V           |
| Input Current  | ±25mA         |
| Output Short-Circuit Duration (Note 2)                   |               |
| Operating Temperature Range                              | -40°C to 85°C |

### PACKAGE/ORDER INFORMATION



Consult factory for Military grade parts.

# **ELECTRICAL CHARACTERISTICS**

 $V_S = 3V$ , 0V;  $V_S = 5V$ , 0V;  $V_{CM} = V_{OUT} = half supply$ ,  $T_A = 25^{\circ}C$ , unless otherwise noted. (Note 3)

| SYMBOL              | PARAMETER                  | CONDITIONS   |   | MIN | TYP | MAX  | UNITS |
|---------------------|----------------------------|--|---|-----|-----|------|-------|
| $\overline{V_{0S}}$ | Input Offset Voltage       | LT1638 N, S Packages   |   |     | 200 | 600  | μV    |
|                     |                            | $0^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 70^{\circ}\text{C}$ | • |     |     | 850  | μV    |
|                     |                            | $-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le 85^{\circ}\text{C}$ | • |     |     | 950  | μV    |
|                     |                            | LT1639 N, S Packages   |   |     | 300 | 700  | μV    |
|                     |                            | $0^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 70^{\circ}\text{C}$ | • |     |     | 950  | μV    |
|                     |                            | $-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le 85^{\circ}\text{C}$ | • |     |     | 1050 | μV    |
|                     |                            | LT1638C MS8 Package  |   |     | 350 | 900  | μV    |
|                     |                            | $0^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 70^{\circ}\text{C}$ | • |     |     | 1150 | μV    |
|                     |                            | $-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le 85^{\circ}\text{C}$ | • |     |     | 1250 | μV    |
|                     | Input Offset Voltage Drift | LT1638/LT1639 N, S Packages  | • |     | 2   | 6    | μV/°C |
|                     | (Note 7)                   | LT1638CMS8   | • |     | 2.5 | 7    | μV/°C |
| I <sub>OS</sub>     | Input Offset Current       |  | • |     | 1   | 6    | nA    |
|                     |                            | V <sub>CM</sub> = 44V (Note 4)                                       | • |     |     | 2.5  | μΑ    |

# **ELECTRICAL CHARACTERISTICS**

 $V_S$  = 3V, 0V;  $V_S$  = 5V, 0V;  $V_{CM}$  =  $V_{OUT}$  = half supply,  $T_A$  = 25°C, unless otherwise noted. (Note 3)

| SYMBOL                    | PARAMETER                             | CONDITIONS  |     | MIN                     | TYP            | MAX        | UNITS                |
|---------------------------|---------------------------------------|---|-----|-------------------------|----------------|------------|----------------------|
| I <sub>B</sub>            | Input Bias Current                    | V <sub>CM</sub> = 44V (Note 4)<br>V <sub>S</sub> = 0V   | •   |                         | 20<br>8<br>0.1 | 50<br>30   | nA<br>μA<br>nA       |
|                           | Input Noise Voltage                   | 0.1Hz to 10Hz   |     |                         | 1              |            | μV <sub>P-P</sub>    |
| en                        | Input Noise Voltage Density           | f = 1kHz  |     |                         | 20             |            | nV/√Hz               |
| in                        | Input Noise Current Density           | f = 1kHz  |     |                         | 0.3            |            | pA/√Hz               |
| R <sub>IN</sub>           | Input Resistance                      | Differential<br>Common Mode, V <sub>CM</sub> = 0V to 44V  |     | 1<br>1.4                | 2.5<br>5.5     |            | MΩ<br>MΩ             |
| C <sub>IN</sub>           | Input Capacitance                     |   |     |                         | 5              |            | pF                   |
|                           | Input Voltage Range                   |   | •   | 0                       |                | 44         | V                    |
| CMRR                      | Common Mode Rejection Ratio           | $V_{CM} = 0V$ to $V_{CC} - 1V$<br>$V_{CM} = 0V$ to 44V (Note 8)   | •   | 88<br>80                | 98<br>88       |            | dB<br>dB             |
| A <sub>VOL</sub> Large-Si | Large-Signal Voltage Gain             | $V_S$ = 3V, $V_0$ = 500mV to 2.5V, $R_L$ = 10k $0^{\circ}C \le T_A \le 70^{\circ}C$ $-40^{\circ}C \le T_A \le 85^{\circ}C$                | •   | 200<br>133<br>100       | 1500           |            | V/mV<br>V/mV<br>V/mV |
|                           |                                       | $V_S = 5V$ , $V_0 = 500$ mV to 4.5V, $R_L = 10$ k $0^{\circ}$ C $\leq T_A \leq 70^{\circ}$ C $-40^{\circ}$ C $\leq T_A \leq 85^{\circ}$ C | • • | 400<br>250<br>200       | 1500           |            | V/mV<br>V/mV<br>V/mV |
| $\overline{V_{0L}}$       | Output Voltage Swing Low              | $V_S = 3V$ , No Load<br>$V_S = 3V$ , $I_{SINK} = 5mA$   | •   |                         | 3<br>250       | 8<br>450   | mV<br>mV             |
|                           |                                       | $V_S = 5V$ , No Load<br>$V_S = 5V$ , $I_{SINK} = 10$ mA   | •   |                         | 3<br>500       | 8<br>700   | mV<br>mV             |
| V <sub>OH</sub>           | Output Voltage Swing High             | $V_S = 3V$ , No Load $V_S = 3V$ , $I_{SOURCE} = 5mA$  | •   | 2.94<br>2.25            | 2.98<br>2.40   |            | V                    |
|                           |                                       | $V_S = 5V$ , No Load<br>$V_S = 5V$ , $I_{SOURCE} = 10mA$  | •   | 4.94<br>3.8             | 4.98<br>4.0    |            | V                    |
| I <sub>SC</sub>           | Short-Circuit Current (Note 2)        | $V_S = 3V$ , Short to GND $V_S = 3V$ , Short to $V_{CC}$  |     | 10<br>15                | 15<br>25       |            | mA<br>mA             |
|                           |                                       | $V_S = 5V$ , Short to GND $V_S = 5V$ , Short to $V_{CC}$  |     | 15<br>15                | 20<br>25       |            | mA<br>mA             |
| PSRR                      | Power Supply Rejection Ratio          | $V_S = 3V \text{ to } 12.5V, V_{CM} = V_0 = 1V$   | •   | 90                      | 100            |            | dB                   |
|                           | Reverse Supply Voltage                | $I_S = -100\mu$ A per Amplifier   | •   | 18                      | 27             |            | V                    |
|                           | Minimum Operating Supply Voltage      |   | •   |                         | 2.4            | 2.7        | V                    |
| Is                        | Supply Current per Amplifier (Note 5) |   | •   |                         | 170            | 230<br>275 | μA<br>μA             |
| GBW                       | Gain Bandwidth Product<br>(Note 4)    | $ f = 1kHz $ $0^{\circ}C \le T_{A} \le 70^{\circ}C $ $-40^{\circ}C \le T_{A} \le 85^{\circ}C $  | •   | 650<br>550<br>500       | 1075           |            | kHz<br>kHz<br>kHz    |
| SR                        | Slew Rate<br>(Note 6)                 | $A_V = -1$ , $R_L = \infty$<br>$0^{\circ}C \le T_A \le 70^{\circ}C$<br>$-40^{\circ}C \le T_A \le 85^{\circ}C$                             | •   | 0.210<br>0.185<br>0.170 | 0.38           |            | V/µs<br>V/µs<br>V/µs |



# **ELECTRICAL CHARACTERISTICS** $v_S = \pm 15 V$ , $v_{CM} = 0 V$ , $v_{OUT} = 0 V$ , $v_{A} = 25 ^{\circ} C$ , unless otherwise noted. (Note 3)

| SYMBOL           | PARAMETER                              | CONDITIONS  |   | MIN                  | TYP           | MAX                  | UNITS                |
|------------------|--|---|---|----------------------|---------------|----------------------|----------------------|
| V <sub>OS</sub>  | Input Offset Voltage                   | LT1638 N, S Packages<br>$0^{\circ}C \le T_A \le 70^{\circ}C$<br>$-40^{\circ}C \le T_A \le 85^{\circ}C$  | • |                      | 250           | 800<br>1000<br>1100  | μV<br>μV<br>μV       |
|                  |  | LT1639 N, S Packages<br>$0^{\circ}C \le T_A \le 70^{\circ}C$<br>$-40^{\circ}C \le T_A \le 85^{\circ}C$  | • |                      | 350           | 900<br>1100<br>1200  | μV<br>μV<br>μV       |
|                  |  | LT1638C MS8 Package<br>$0^{\circ}C \le T_A \le 70^{\circ}C$<br>$-40^{\circ}C \le T_A \le 85^{\circ}C$   | • |                      | 400           | 1050<br>1250<br>1350 | μV<br>μV<br>μV       |
|                  | Input Offset Voltage Drift<br>(Note 7) | LT1638/LT1639 N, S Packages<br>LT1638CMS8   | • |                      | 2<br>2.5      | 6<br>7               | μV/°C<br>μV/°C       |
| I <sub>OS</sub>  | Input Offset Current                   |   | • |                      | 1             | 6                    | nA                   |
| I <sub>B</sub>   | Input Bias Current                     |   | • |                      | 20            | 50                   | nA                   |
|                  | Input Noise Voltage                    | 0.1Hz to 10Hz   |   |                      | 1             |                      | μV <sub>P-P</sub>    |
| e <sub>n</sub>   | Input Noise Voltage Density            | f = 1kHz  |   |                      | 20            |                      | nV/√Hz               |
| i <sub>n</sub>   | Input Noise Current Density            | f = 1kHz  |   |                      | 0.3           |                      | pA/√Hz               |
| R <sub>IN</sub>  | Input Resistance                       | Differential<br>Common Mode, V <sub>CM</sub> = −15V to 14V  |   | 1                    | 2.5<br>500    |                      | MΩ<br>MΩ             |
| C <sub>IN</sub>  | Input Capacitance                      |   |   |                      | 4.5           |                      | pF                   |
|                  | Input Voltage Range                    |   | • | -15                  |               | 29                   | V                    |
| CMRR             | Common Mode Rejection Ratio            | $V_{CM} = -15V \text{ to } 29V$   | • | 80                   | 88            |                      | dB                   |
| A <sub>VOL</sub> | Large-Signal Voltage Gain              | $V_0 = \pm 14V, R_L = 10k$<br>$0^{\circ}C \le T_A \le 70^{\circ}C$<br>$-40^{\circ}C \le T_A \le 85^{\circ}C$  | • | 200<br>125<br>100    | 500           |                      | V/mV<br>V/mV<br>V/mV |
| V <sub>OL</sub>  | Output Voltage Swing                   | No Load<br>I <sub>OUT</sub> = ±10mA   | • | 14.9<br>13.7         | 14.95<br>14.0 |                      | V                    |
| I <sub>SC</sub>  | Short-Circuit Current (Note 2)         | Short to GND $0^{\circ}\text{C} \le T_{A} \le 70^{\circ}\text{C}$ $-40^{\circ}\text{C} \le T_{A} \le 85^{\circ}\text{C}$                                      | • | 25<br>20<br>15       | 40            |                      | mA<br>mA<br>mA       |
| PSRR             | Power Supply Rejection Ratio           | $V_S = \pm 1.5 V \text{ to } \pm 22 V$  | • | 90                   | 100           |                      | dB                   |
| I <sub>S</sub>   | Supply Current per Amplifier           |   | • |                      | 205           | 280<br>350           | μA<br>μA             |
| GBW              | Gain Bandwidth Product                 | $ f = 1kHz $ $0^{\circ}C \le T_{A} \le 70^{\circ}C $ $-40^{\circ}C \le T_{A} \le 85^{\circ}C $  | • | 750<br>650<br>600    | 1200          |                      | kHz<br>kHz<br>kHz    |
| SR               | Slew Rate                              | $ \begin{aligned} A_V &= -1, \ R_L = \infty, \ V_0 = \pm 10V, \\ 0^\circ C &\leq T_A \leq 70^\circ C \\ -40^\circ C &\leq T_A \leq 85^\circ C \end{aligned} $ | • | 0.225<br>0.2<br>0.18 | 0.4           |                      | V/μs<br>V/μs<br>V/μs |

The • denotes specifications which apply over the full specified temperature range.

**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:** A heat sink may be required to keep the junction temperature below absolute maximum. This depends on the power supply voltage and how many amplifiers are shorted.

**Note 3:** The LT1638C/LT1639C are guaranteed to meet  $0^{\circ}$ C to  $70^{\circ}$ C specifications and are designed, characterized and expected to meet the extended temperature limits, but are not tested at  $-40^{\circ}$ C and  $85^{\circ}$ C. The LT1638I/LT1639I are guaranteed to meet the extended temperature limits.

**Note 4:**  $V_S = 5V$  limits are guaranteed by correlation to  $V_S = 3V$  and  $V_S = \pm 15V$  tests.

**Note 5:**  $V_S = 3V$  limits are guaranteed by correlation to  $V_S = 5V$  and  $V_S = \pm 15V$  tests.

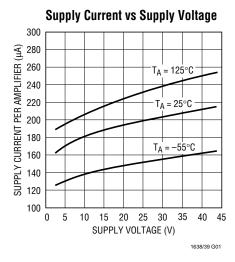
**Note 6:** Guaranteed by correlation to slew rate at  $V_S = \pm 15V$  and GBW at  $V_S = 3V$  and  $V_S = \pm 15V$  tests.

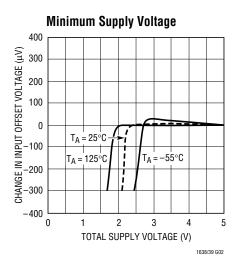
Note 7: This parameter is not 100% tested.

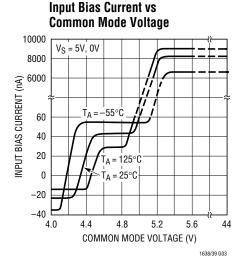
**Note 8:** The spec implies a typical offset voltage at  $V_{CM}$  = 44 of 2mV and a maximum offset voltage at  $V_{CM}$  = 44 of 5mV.

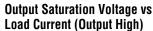


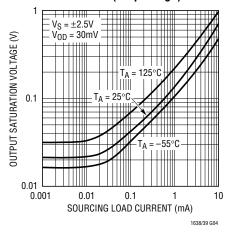
### TYPICAL PERFORMANCE CHARACTERISTICS

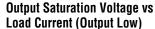


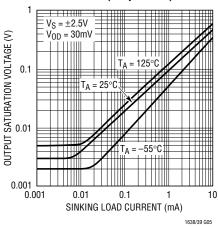




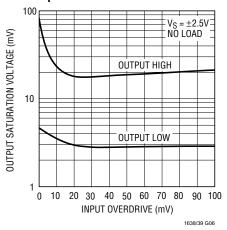




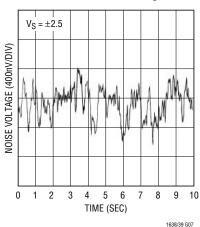




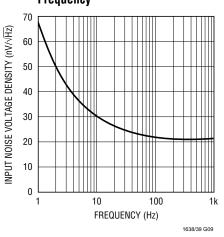
Output Saturation Voltage vs Input Overdrive



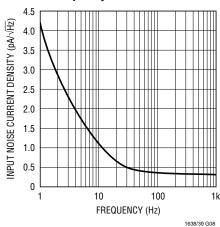
#### 0.1Hz to 10Hz Noise Voltage



### Noise Voltage Density vs Frequency

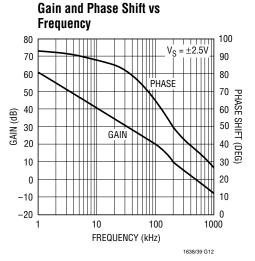


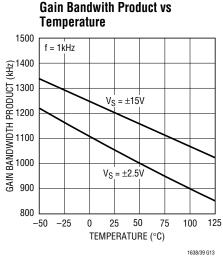
# Input Noise Current Density vs Frequency

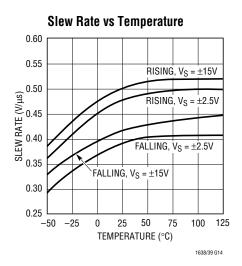


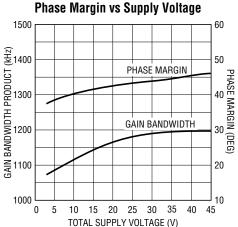


### TYPICAL PERFORMANCE CHARACTERISTICS

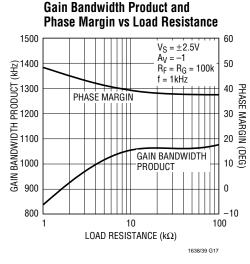


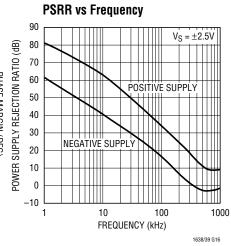


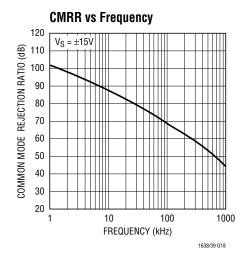


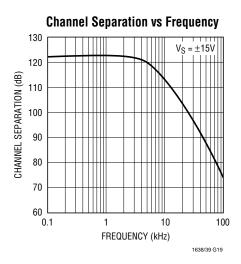


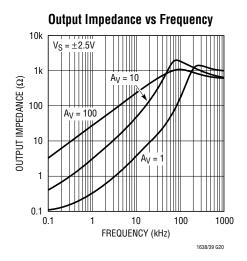
**Gain Bandwidth Product and** 





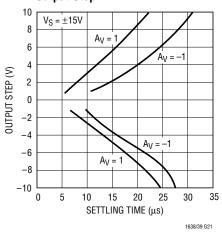




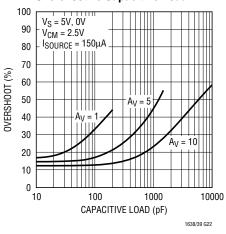


### TYPICAL PERFORMANCE CHARACTERISTICS

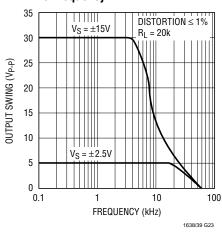
#### Settling Time to 0.1% vs **Output Step**



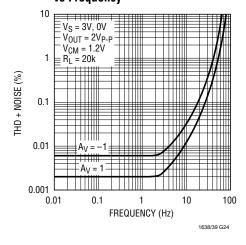
#### Capacitive Load Handling, **Overshoot vs Capacitive Load**



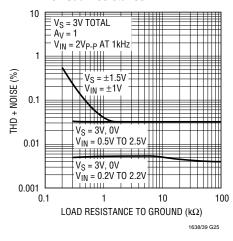
#### **Undistorted Output Swing** vs Frequency



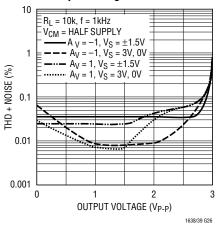
### Total Harmonic Distortion + Noise vs Frequency



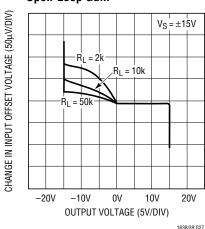
#### **Total Harmonic Distortion + Noise** vs Load Resistance



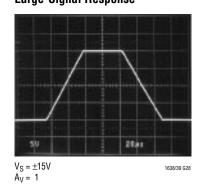
**Total Harmonic Distortion + Noise** vs Output Voltage



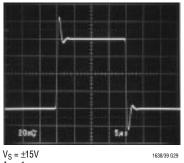
#### Open-Loop Gain



#### Large-Signal Response



#### **Small-Signal Response**





### APPLICATIONS INFORMATION

### **Supply Voltage**

The positive supply pin of the LT1638/LT1639 should be bypassed with a small capacitor (typically  $0.1\mu F$ ) within an inch of the pin. When driving heavy loads an additional  $4.7\mu F$  electrolytic capacitor should be used. When using split supplies, the same is true for the negative supply pin.

The LT1638/LT1639 are protected against reverse battery voltages up to 18V. In the event a reverse battery condition occurs, the supply current is less than 1nA.

The LT1638/LT1639 can be shut down by removing V<sup>+</sup>. In this condition the input bias current is less than 0.1nA, even if the inputs are 44V above the negative supply.

At temperatures greater than  $70^{\circ}$ C, when operating the LT1638/LT1639 on total supplies of 10V or more, the supply must not be brought up faster than  $1V/\mu s$ . Increasing the bypass capacitor and/or adding a small resistor in series with the supply will limit the rise time.

### **Inputs**

The LT1638/LT1639 have two input stages, NPN and PNP (see the Simplified Schematic), resulting in three distinct operating regions as shown in the Input Bias Current vs Common Mode typical performance curve.

For input voltages about 0.8V or more below V+, the PNP input stage is active and the input bias current is typically -20nA. When the input common mode voltage is within 0.5V of the positive rail, the NPN stage is operating and the input bias current is typically 40nA. Increases in temperature will cause the voltage at which operation switches from the PNP input stage to the NPN input stage to move towards V+. The input offset voltage of the NPN stage is untrimmed and is typically  $600\mu\text{V}$ .

A Schottky diode in the collector of each NPN transistor allow the LT1638/LT1639 to operate over the top, with either or both of its inputs above V<sup>+</sup>. At about 0.3V above V<sup>+</sup> the NPN input transistor is fully saturated and the input bias current is typically  $8\mu A$  at room temperature. The input offset voltage is typically 2mV when operating above V<sup>+</sup>. The LT1638/LT1639 will operate with its inputs 44V above V<sup>-</sup> regardless of V<sup>+</sup>.

The inputs are protected against excursions as much as 22V below V<sup>-</sup> by an internal 1k resistor in series with each input and a diode from the input to the negative supply. The input stage of the LT1638/LT1639 incorporates phase reversal protection to prevent the output from phase reversing for inputs up to 22V below V<sup>-</sup>. There are no clamping diodes between the inputs and the maximum differential input voltage is 44V.

### Output

The output of the LT1638/LT1639 can swing within 20mV of the positive rail with no load, and within 3mV of the negative rail with no load. When monitoring voltages within 20mV of the positive rail or within 3mV of the negative rail, gain should be taken to keep the output from clipping. The LT1638/LT1639 are capable of sinking and sourcing over 40mA on  $\pm 15$ V supplies; sourcing current capability is reduced to 20mA at 5V total supplies as noted in the electrical characteristics.

The LT1638/LT1639 are internally compensated to drive at least 200pF of capacitance under any output loading conditions. A  $0.22\mu F$  capacitor in series with a  $150\Omega$  resistor between the output and ground will compensate these amplifiers for larger capacitive loads, up to 1000pF, at all output currents.

### **Distortion**

There are two main contributors of distortion in op amps: output crossover distortion as the output transitions from sourcing to sinking current and distortion caused by nonlinear common mode rejection. If the op amp is operating inverting there is no common mode induced distortion. If the op amp is operating in the PNP input stage (input is not within 0.8V of V<sup>+</sup>), the CMRR is very good, typically 98dB. When the LT1638 switches between input stages there is significant nonlinearity in the CMRR. Lower load resistance increases the output crossover distortion, but has no effect on the input stage transition distortion. For lowest distortion the LT1638/LT1639 should be operated single supply, with the output always sourcing current and with the input voltage swing between ground and (V<sup>+</sup> – 0.8V). See the Typical Performance Characteristics curves.



### APPLICATIONS INFORMATION

#### Gain

The open-loop gain is almost independent of load when the output is sourcing current. This optimizes performance in single supply applications where the load is returned to ground. The typical performance curve of Open-Loop Gain for various loads shows the details.

### TYPICAL APPLICATIONS

With 1.2MHz bandwidth, Over-The-Top capability, reverse-battery protection and rail-to-rail input and output features, the LT1638/LT1639 are ideal candidates for general purpose applications.

The lowpass slope limiting filter in Figure 1 limits the maximum dV/dT (not frequency) that it passes. When the input signal differs from the output by one forward diode drop, D1 or D2 will turn on. With a diode on, the voltage across R2 will be constant and a fixed current,  $V_{DIODE}/R2$ , will flow through capacitor C1, charging it linearly instead of exponentially. The maximum slope that the circuit will pass is equal to  $V_{DIODE}$  divided by (R2)(C1). No matter how fast the input changes the output will never change any faster than the dV/dT set by the diodes and (R2)(C).

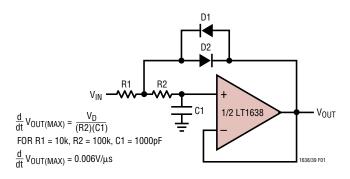
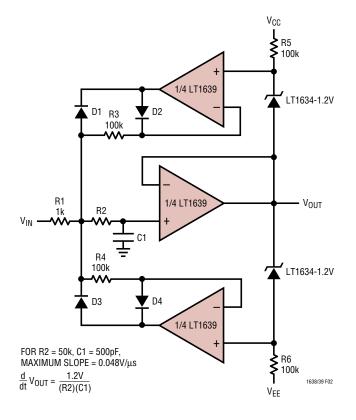


Figure 1. Lowpass Slope Limiting Filter

A modification of this application is shown in Figure 2 using references instead of diodes to set the maximum slope. By using references, the slope is independent of temperature. A scope photo shows a  $1V_{P-P}$ , 2kHz input signal with a 2V pulse added to the sine wave; the circuit passes the 2kHz signal but limits the slope of the pulse.

The application in Figure 3 utilizes the Over-The-Top capabilities of the LT1638. The  $0.2\Omega$  resistor senses the load current while the op amp and NPN transistor form a closed loop making the collector current of Q1



### Response of Slope Limiting Filter

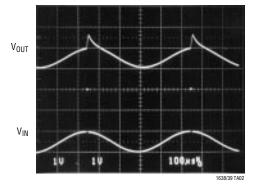


Figure 2. Lowpass Slope Limiting Filter with OTC



### TYPICAL APPLICATIONS

proportional to the load current. As a convenient monitor, the 2k load resistor converts the current into a voltage. The positive supply rail,  $V^+$ , is not limited to the 5V supply of the op amp and could be as high as 44V.

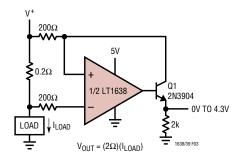


Figure 3. Positive Supply Rail Current Sense

The Figure 4 application uses the LT1638 in conjunction with the LT1634 micropower shunt reference. The supply current of the op amp also biases the reference. The drop across resistor R1 is fixed at 1.2V generating an output current equal to 1.2V/R1.

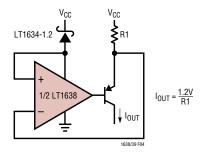
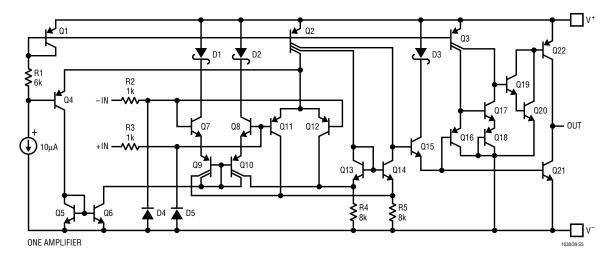


Figure 4. Current Source

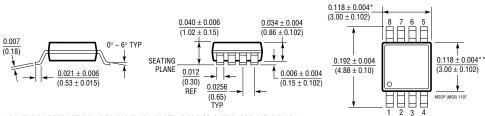
### SIMPLIFIED SCHEMATIC



# PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.

### MS8 Package 8-Lead Plastic MSOP

(LTC DWG # 05-08-1660)



<sup>\*</sup> DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH,

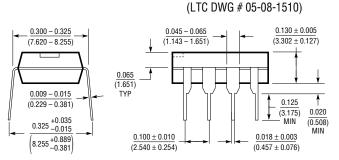
PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

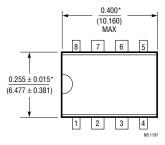
\* DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.

INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

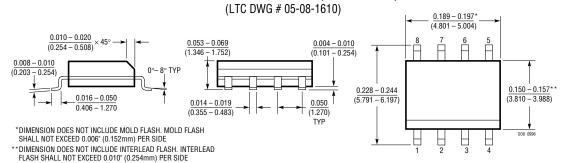
# PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.

### N8 Package 8-Lead PDIP (Narrow 0.300)

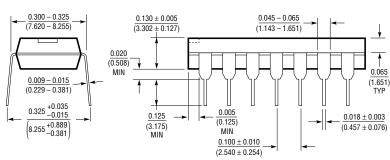


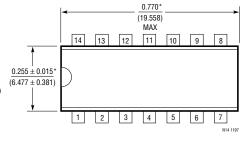


#### S8 Package 8-Lead Plastic Small Outline (Narrow 0.150)



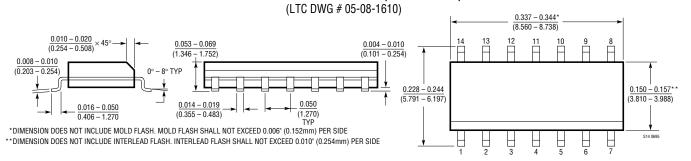
#### N Package 14-Lead PDIP (Narrow 0.300) (LTC DWG # 05-08-1510)





\*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

#### S Package 14-Lead Plastic Small Outline (Narrow 0.150)



<sup>\*</sup>THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

### TYPICAL APPLICATION

The battery monitor in Figure 5 also demonstrates the LT1638's ability to operate with its inputs above the positive rail. In this application, a conventional amplifier would be limited to a battery voltage between 5V and ground, but the LT1638 can handle battery voltages as high as 44V. When the battery is charging, Amp B senses the voltage drop across  $R_S$ . The output of Amp B causes Q2 to drain sufficient current through  $R_B$  to balance the input of Amp B. Likewise, Amp A and Q1 form a closed

loop when the battery is discharging. The current through Q1 or Q2 is proportional to the current in  $R_S$  and this current flows into  $R_G$  and is converted into a voltage. Amp D buffers and amplifies the voltage across  $R_G$ . Amp C compares the output of Amp A and Amp B to determine the polarity of current through  $R_S$ . The scale factor for  $V_{OUT}$  with S1 open is 1V/A. With S1 closed the scale factor is 1V/100mA and currents as low as  $500\mu A$  can be measured.

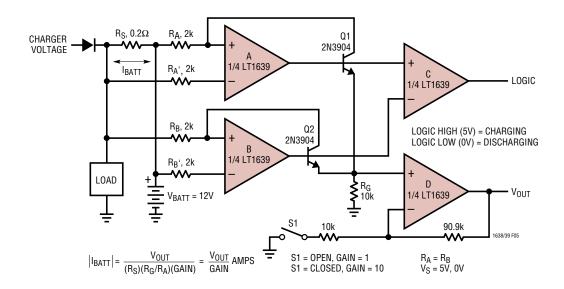


Figure 5. Battery Monitor

### RELATED PARTS

| PART NUMBER                    | DESCRIPTION  | COMMENTS   |
|--------------------------------|--|--|
| LT1078/LT1079<br>LT2078/LT2079 | Dual/Quad 55μA Max, Single Supply, Precision Op Amps                     | Input/Output Common Mode Includes Ground, 70μV V <sub>OS(MAX)</sub> and 2.5μV/°C Drift (Max), 200kHz GBW, 0.07V/μs Slew Rate                 |
| LT1178/LT1179<br>LT2178/LT2179 | Dual/Quad 17μA Max, Single Supply, Precison Op Amps                      | Input/Output Common Mode Includes Ground, 70μV V <sub>OS(MAX)</sub> and 4μV/°C Drift (Max), 85kHz GBW, 0.04V/μs Slew Rate                    |
| LT1366/LT1367                  | Dual/Quad Precision, Rail-to-Rail Input and Output Op Amps               | 475μV V <sub>OS(MAX)</sub> , 500V/mV A <sub>VOL(MIN)</sub> , 400kHz GBW  |
| LT1490/LT1491                  | Dual/Quad Over-The-Top Micropower, Rail-to-Rail Input and Output Op Amps | Single Supply Input Range: -0.4V to 44V, Micropower 50µA per Amplifier, Rail-to-Rail Input and Output, 200kHz GBW                            |
| LT1636                         | Single Over-The-Top Micropower Rail-to-Rail Input and Output Op Amp      | 55µA Supply Current, V <sub>CM</sub> Extends 44V above V <sub>EE</sub> ,<br>Independent of V <sub>CC</sub> ; MSOP Package, Shutdown Function |

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